

Features

- Split Gate Trench Mosfet Technology
- · Excellent Stability and Uniformity
- Halogen Free ."Green" Device (Note 1)
- · Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

• Operating Junction Temperature Range: -55°C to +150°C

• Storage Temperature Range: -55°C to +150°C

• Thermal Resistance: 62.5°C/W Junction to Ambient(Note 2)

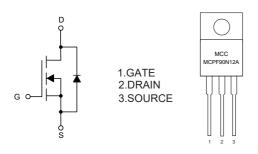
• Thermal Resistance: 1.6°C/W Junction to Case

Parameter		Symbol	Rating	Unit	
Drain -Source Voltage		V _{DS}	120	V	
Gate -Source Volltage	V _{GS}	±20	V		
Drain Current-Continuous	T _C =25°C		90	А	
	T _C =100°C	l _D	56		
Drain Current-Pulse(Note 3)	I _{DM}	360	Α		
Power Dissipation ^(Note 4)		P _D	78	W	
Single Pulsed Avalanche Energy ^(Note 5)		E _{AS}	441	mJ	

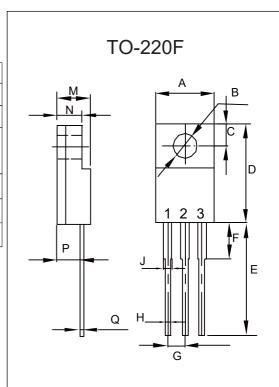
Note:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The value of R θ JA is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C.
- 3. Repetitive rating; pulse width limited by max. junction temperature.
- 4. $\ensuremath{P_{\text{D}}}$ is based on max. junction temperature, using junction-Case thermal resistance.
- 5. T_J =25 °C, V_{DD} =50V, R_G =25 Ω , V_{GS} =10V,L=2mH.

Internal Structure and Marking Code



N-CHANNEL MOSFET



	DIMENSIONS					
DIM INCHES		HES	MM		NOTE	
Dilvi	MIN	MAX	MIN	MAX	NOIL	
Α	0.381	0.406	9.70	10.30		
В	0.118	0.138	3.00	3.50	Ф	
С	0.124	0.139	3.15	3.55		
D	0.610	0.634	15.50	16.10		
Е	0.496	0.535	12.60	13.60		
F	0.134	0.150	3.40	3.80		
G	0.092	0.108	2.34	2.74		
Н	0.027	0.035	0.70	0.90		
J	0.044	0.056	1.12	1.42		
M	0.173	0.193	4.40	4.90		
N	0.098	0.114	2.50	2.90		
Р	0.085	0.100	2.15	2.55		
Q	0.016	0.024	0.40	0.60		



Electrical Characteristics @ 25°C (Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static Characteristics			,	1	1		
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	120			V	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =120V, V _{GS} =0V			1	uA	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	2.0	3.0	V	
Drain-Source On-Resistance	D	V _{GS} =10V, I _D =45A		7	9 mΩ		
	$R_{DS(on)}$	V _{GS} =4.5V, I _D =20A		8.5	11	11177	
Gate resistance	R_G	V _{GS} =0V,f=1MHz		8.0		Ω	
Diode Characteristics							
Continuous Body Diode Current	Is				90	Α	
Body Diode Voltage	V _{SD}	I _{SD} =20A, V _{GS} =0V			1.2	V	
Reverse Recovery Charge	Q _{rr}	- I _F =20A,di/dt=100A/μs		176		nC	
Reverse Recovery Time	t _{rr}	1 F-20Λ, αι/αι-100Λ/μ5		85		ns	
Dynamic Characteristics							
Input Capacitance	C _{iss}			4604			
Output Capacitance	C _{oss}	V _{DS} =60V,V _{GS} =0V,f=1MHz		430		pF	
Reverse Transfer Capacitance	C _{rss}			7.4			
Total Gate Charge	Qg			67.5			
Gate-Source Charge	Q _{gs}	V_{DS} =60V, V_{GS} =10V, I_{D} =20A		13.5		nC	
Gate-Drain Charge	Q_{gd}			10			
Turn-On Delay Time	t _{d(on)}			16			
Turn-On Rise Time	t _r	V _{DD} =60V,I _D =20A,		8.7		ns	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.2 Ω		43			
Turn-Off Fall Time	t _f			11			



Curve Characteristics

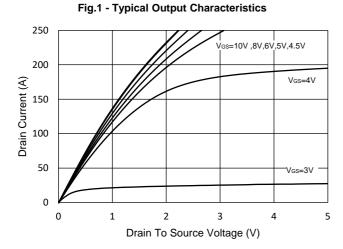


Fig.2 - Transfer Characteristic

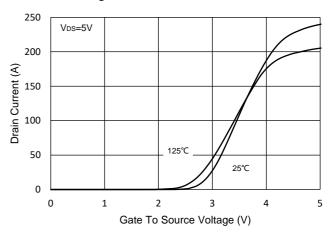


Fig.3 - R_{DS(ON)} - V_{GS}

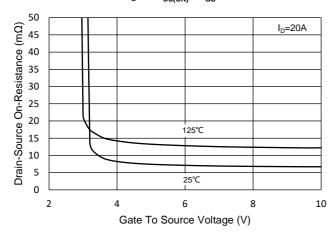


Fig.4 - R_{DS(ON)} - I_D

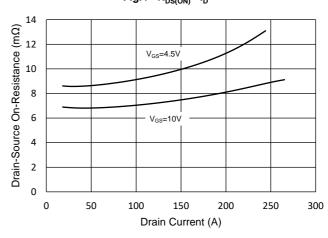


Fig.5 - Capacitance Characteristics

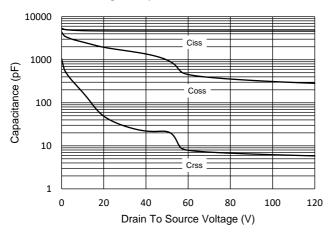
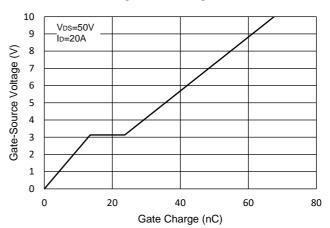
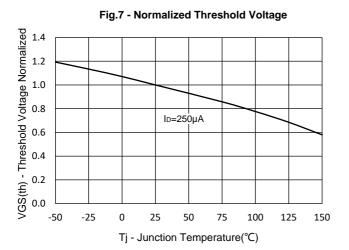


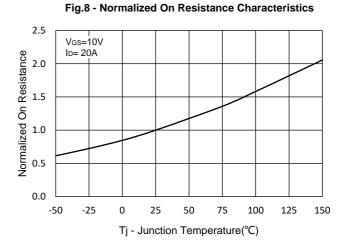
Fig.6 - Gate Charge

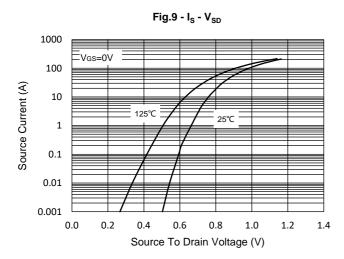


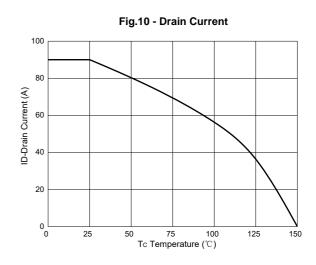


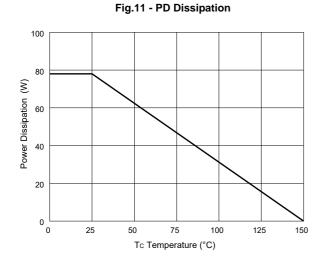
Curve Characteristics













Curve Characteristics

Fig.12 - Safe Operation Area

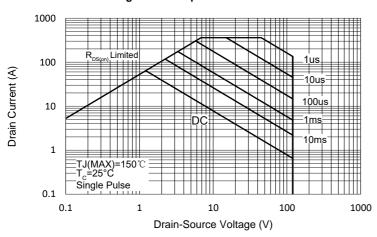
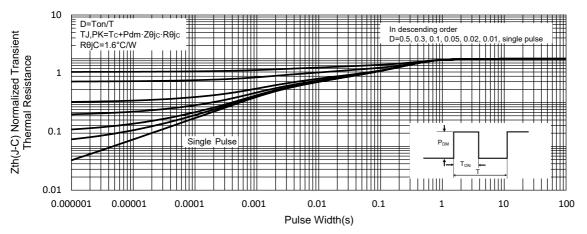


Fig.13 - Normalized Transient Thermal Impedance





Ordering Information

Device	Packing		
Part Number-BP	Bulk:50pcs/Tube,1Kpcs/Box,5Kpcs/Carton		

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